

# MOS FIELD EFFECT TRANSISTOR 2SK3204

# SWITCHING N-CHANNEL POWER MOS FET INDUSTRIAL USE

### DESCRIPTION

The 2SK3204 is N-Channel MOS Field Effect Transistor designed for high current switching applications.

#### ★ FEATURES

\* \*

- Low on-state resistance :
  - $R_{DS(on)1} = 34 \text{ m}\Omega \text{ (MAX.)} (V_{GS} = 10 \text{ V}, \text{ ID} = 8 \text{ A})$
  - $R_{DS(on)2} = 50 \text{ m}\Omega \text{ (MAX.)} (V_{GS} = 4 \text{ V}, \text{ ID} = 8 \text{ A})$
- Low Ciss : Ciss = 940 pF (TYP.)
- Built-in gate protection diode.

#### ABSOLUTE MAXIMUM RATINGS (TA = 25 °C)

Drain to Source Voltage	Vdss	60	V
Gate to Source Voltage	VGSS(AC)	±20	V
Gate to Source Voltage	VGSS(DC)	+20, -10	V
Drain Current (DC)	D(DC)	±15	А
Drain Current (pulse) Note1	D(pulse)	±45	А
Total Power Dissipation (T <sub>A</sub> = 25 °C)	P⊤	1.8	W
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg	–55 to +150	°C
Single Avalanche Current Note2	las	15	А
Single Avalanche Energy Note2	Eas	22.5	mJ
Notes 1 DW < 10 up Duty Cycle < 1.0/			

**Notes 1.** PW  $\leq$  10  $\mu$ s, Duty Cycle  $\leq$  1 %

**2.** Starting T<sub>ch</sub> = 25 °C, R<sub>G</sub> = 25  $\Omega$ , V<sub>GS</sub> = 20 V $\rightarrow$ 0 V

## THERMAL RESISTANCE

h-A) 69.4 °C/W
(C

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The mark  $\star$  shows major revised points.

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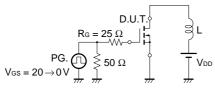
# **\*** ORDERING INFORMATION

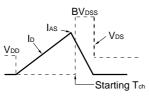
PART NUMBER	PACKAGE	
2SK3204	MP-10	

### **★** ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25 °C)

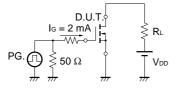
PARAMATERS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Drain to Source On-state Resistance	RDS(on)1	Vgs = 10 V, Id = 8 A		25	34	mΩ
	RDS(on)2	Vgs = 4 V, Id = 8 A		35	50	mΩ
Gate to Source Cut-off Voltage	VGS(off)	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 1 mA	1.0	1.5	2.0	V
Forward Transfer Admittance	y <sub>fs</sub>	Vds = 10 V, Id = 8 A	8.0	14		S
Drain Leakage Current	IDSS	Vds = 60 V, Vgs = 0 V			10	μA
Gate to Source Leakage Current	lgss	$V_{GS} = \pm 20 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$			±10	μA
Input Capacitance	Ciss	V <sub>DS</sub> = 10 V, V <sub>GS</sub> = 0 V, f = 1 MHz		940		pF
Output Capacitance	Coss			290		pF
Reverse Transfer Capacitance	Crss			120		pF
Turn-on Delay Time	td(on)	$I_D = 8 \text{ A}, V_{GS(on)} = 10 \text{ V}, V_{DD} = 30 \text{ V},$		17		ns
Rise Time	tr	R <sub>G</sub> = 10 Ω		150		ns
Turn-off Delay Time	td(off)			58		ns
Fall Time	tr			52		ns
Total Gate Charge	QG	$I_D = 15 \text{ A}, V_{DD} = 48 \text{ V}, V_{GS(on)} = 10 \text{ V}$		25		nC
Gate to Source Charge	Q <sub>GS</sub>			2.9		nC
Gate to Drain Charge	Qgd			7.5		nC
Body Diode Forward Voltage	VF(S-D)	IF = 15 A, VGS = 0 V		0.92		V
Reverse Recovery Time	trr	IF = 15 A, VGs = 0 V,		45		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/µs		81		nC

### ★ TEST CIRCUIT 1 AVALANCHE CAPABILITY

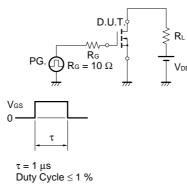


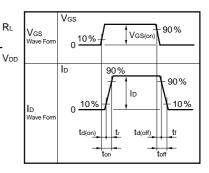


#### ★ TEST CIRCUIT 3 GATE CHARGE



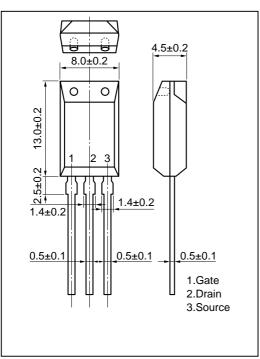
#### ★ TEST CIRCUIT 2 SWITCHING TIME



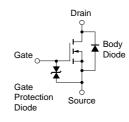


#### PACKAGE DRAWING (Unit : mm)





#### **EQUIVALENT CIRCUIT**



Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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